

# **3A Dual High-Speed Power MOSFET Drivers**

#### Features

- High Peak Output Current: 4.5A (typical)
- Wide Input Supply Voltage Operating Range:
   4.5V to 18V
- High Capacitive Load Drive Capability:
  - 1800 pF in 12 ns
- Short Delay Times: 40 ns (typical)
- Matched Rise/Fall Times
- · Low Supply Current:
  - With Logic '1' Input 1.0 mA (maximum)
- With Logic '0' Input 150 µA (maximum)
- Low Output Impedance: 2.5Ω (typical)
- Latch-Up Protected: Will Withstand 1.5A Reverse Current
- Logic Input Will Withstand Negative Swing Up To 5V
- Pin compatible with the TC4423/TC4424/TC4425 and TC4426A/TC4427A/TC4428A devices
- Space-saving 8-Pin 150 mil body SOIC and 8-Pin 6x5 DFN Packages

### Applications

- · Switch Mode Power Supplies
- Pulse Transformer Drive
- Line Drivers
- · Direct Drive of Small DC Motors

### **General Description**

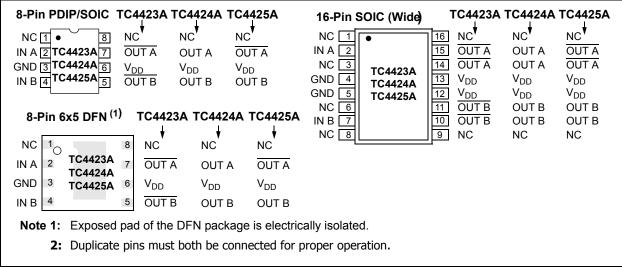
The TC4423A/TC4424A/TC4425A devices are a family of dual-output 3A buffers/MOSFET drivers. These devices are improved versions of the earlier TC4423/ TC4424/TC4425 dual-output 3A driver family. This improved version features higher peak output current drive capability, lower shoot-throught current, matched rise/fall times and propagation delay times. The TC4423A/TC4424A/TC4425A devices are pincompatible with the existing TC4423/TC4424/TC4425 family. An 8-pin SOIC package option has been added to the family. The 8-pin DFN package option offers increased power dissipation capability for driving heavier capacitive or resistive loads.

The TC4423A/TC4424A/TC4425A MOSFET drivers can easily charge and discharge 1800 pF gate capacitance in under 20 ns, provide low enough impedances in both the on and off states to ensure the MOSFET's intended state will not be affected, even by large transients.

The TC4423A/TC4424A/TC4425A inputs may be driven directly from either TTL or CMOS (2.4V to 18V). In addition, the 300 mV of built-in hysteresis provides noise immunity and allows the device to be driven from slow rising or falling waveforms.

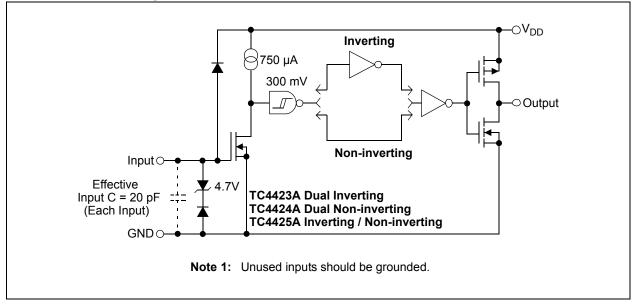
The TC4423A/TC4424A/TC4425A dual-output 3A MOSFET driver family is offerd with a -40°C to +125°C temperature rating, making it useful in any wide temperature range application.

### Package Types



# TC4423A/TC4424A/TC4425A

# Functional Block Diagram<sup>(1)</sup>



# 1.0 ELECTRICAL CHARACTERISTICS

### Absolute Maximum Ratings †

Supply Voltage+20	V
Input Voltage, IN A or IN B (V <sub>DD</sub> + 0.3V) to (GND - 5 <sup>V</sup>	√)
Package Power Dissipation (T <sub>A</sub> =50°C)	
8L PDIP1.2	N
8L SOIC 0.61	N
16L SOIC1.1	N
8L DFN Note	3

**† Notice:** Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

# DC CHARACTERISTICS (NOTE 2)

Electrical Specifications: Unle	<b>Electrical Specifications:</b> Unless otherwise indicated, $T_A = +25^{\circ}C$ , with 4.5V $\leq V_{DD} \leq 18V$ .								
Parameters	Sym	Min	Тур	Max	Units	Conditions			
Input									
Logic '1', High Input Voltage	V <sub>IH</sub>	2.4	1.5	_	V				
Logic '0', Low Input Voltage	V <sub>IL</sub>	—	1.3	0.8	V				
Input Current	I <sub>IN</sub>	-1		1	μA	$0V \le V_{IN} \le V_{DD}$			
Input Voltage	V <sub>IN</sub>	-5	_	V <sub>DD</sub> +0.3	V				
Output									
High Output Voltage	V <sub>OH</sub>	V <sub>DD</sub> - 0.025		_	V	DC Test			
Low Output Voltage	V <sub>OL</sub>			0.025	V	DC Test			
Output Resistance, High	R <sub>OH</sub>	—	2.2	3.0	Ω	I <sub>OUT</sub> = 10 mA, V <sub>DD</sub> = 18V			
Output Resistance, Low	R <sub>OL</sub>		2.8	3.5	Ω	I <sub>OUT</sub> = 10 mA, V <sub>DD</sub> = 18V			
Peak Output Current	I <sub>PK</sub>		4.5	_	Α	10V≤ V <sub>DD</sub> ≤18V (Note 2)			
Latch-Up Protection With- stand Reverse Current	I <sub>REV</sub>	—	>1.5		A	Duty cycle $\leq$ 2%, t $\leq$ 300 µsec.			
Switching Time (Note 1)						•			
Rise Time	t <sub>R</sub>	—	12	21	ns	Figure 4-1, Figure 4-2, C <sub>L</sub> = 1800 pF			
Fall Time	t <sub>F</sub>	—	12	21	ns	Figure 4-1, Figure 4-2, C <sub>L</sub> = 1800 pF			
Delay Time	t <sub>D1</sub>	—	40	48	ns	Figure 4-1, Figure 4-2, C <sub>L</sub> = 1800 pF			
Delay Time	t <sub>D2</sub>	—	41	48	ns	Figure 4-1, Figure 4-2, C <sub>L</sub> = 1800 pF			
Power Supply	•	1							
Supply Voltage	V <sub>DD</sub>	4.5		18	V				
Power Supply Current	I <sub>S</sub>	—	1.0	2.0	mA	V <sub>IN</sub> = 3V (Both inputs)			
	I <sub>S</sub>	_	0.15	0.25	mA	V <sub>IN</sub> = 0V (Both inputs)			
	· · ·				· · · · · · · · · · · · · · · · · · ·				

Note 1: Switching times ensured by design.

2: Tested during characterization, not production tested.

3: Package power dissipation is dependent on the copper pad area on the PCB.

# DC CHARACTERISTICS (OVER OPERATING TEMPERATURE RANGE)

<b>Electrical Specifications:</b> Unless otherwise indicated, operating temperature range with $4.5V \le V_{DD} \le 18V$ .									
Parameters	Sym	Min	Тур	Max	Units	Conditions			
Input									
Logic '1', High Input Voltage	V <sub>IH</sub>	2.4	_	—	V				
Logic '0', Low Input Voltage	V <sub>IL</sub>	—	_	0.8	V				
Input Current	I <sub>IN</sub>	-10	_	+10	μA	$0V \le V_{IN} \le V_{DD}$			
Output									
High Output Voltage	V <sub>OH</sub>	V <sub>DD</sub> - 0.025	_	—	V				
Low Output Voltage	V <sub>OL</sub>	_		0.025	V				
Output Resistance, High	R <sub>OH</sub>	_	3.1	6	Ω	I <sub>OUT</sub> = 10 mA, V <sub>DD</sub> = 18V			
Output Resistance, Low	R <sub>OL</sub>	—	3.7	7	Ω	I <sub>OUT</sub> = 10 mA, V <sub>DD</sub> = 18V			
Switching Time (Note 1)									
Rise Time	t <sub>R</sub>	—	20	31	ns	Figure 4-1, Figure 4-2, C <sub>L</sub> = 1800 pF			
Fall Time	t <sub>F</sub>	—	22	31	ns	Figure 4-1, Figure 4-2, C <sub>L</sub> = 1800 pF			
Delay Time	t <sub>D1</sub>	—	50	66	ns	Figure 4-1, Figure 4-2, C <sub>L</sub> = 1800 pF			
Delay Time	t <sub>D2</sub>	—	50	66	ns	Figure 4-1, Figure 4-2, C <sub>L</sub> = 1800 pF			
Power Supply		· · ·		·		•			
Power Supply Current	۱ <sub>S</sub>	—	2.0 0.2	3.0 0.3	mA	V <sub>IN</sub> = 3V (Both inputs) V <sub>IN</sub> = 0V (Both inputs)			

Note 1: Switching times ensured by design.

# **TEMPERATURE CHARACTERISTICS**

<b>Electrical Specifications:</b> Unless otherwise noted, all parameters apply with 4.5V $\leq$ V <sub>DD</sub> $\leq$ 18V.									
Parameters	Sym	Min	Тур	Max	Units	Conditions			
Temperature Ranges									
Specified Temperature Range (V)	T <sub>A</sub>	-40	_	+125	°C				
Maximum Junction Temperature	Τ <sub>J</sub>	—	_	+150	°C				
Storage Temperature Range	T <sub>A</sub>	-65	_	+150	°C				
Package Thermal Resistances									
Thermal Resistance, 8L-6x5 DFN	$\theta_{JA}$	—	33.2		°C/W	Typical four-layer board with vias to ground plane			
Thermal Resistance, 8L-PDIP	$\theta_{JA}$	_	84.6	_	°C/W				
Thermal Resistance, 8L-SOIC	$\theta_{JA}$		163	_	°C/W				
Thermal Resistance, 16L-SOIC	$\theta_{JA}$		90	_	°C/W				

# 2.0 TYPICAL PERFORMANCE CURVES

Note: Unless otherwise indicated,  $T_A = +25^{\circ}C$  with 4.5V <=  $V_{DD}$  <= 18V.

**Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

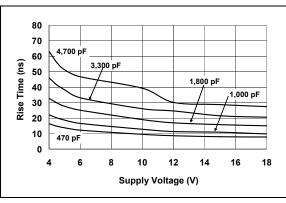


FIGURE 2-1: Rise Time vs. Supply Voltage.

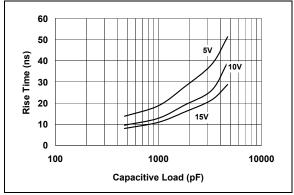


FIGURE 2-2: Rise Time vs. Capacitive Load.

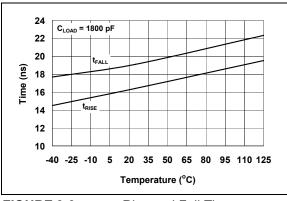


FIGURE 2-3: Temperature.

Rise and Fall Times vs.

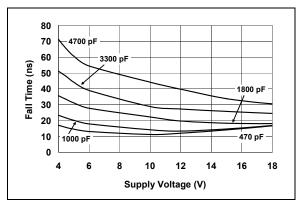


FIGURE 2-4: Fall Time vs. Supply Voltage.

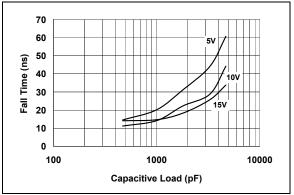


FIGURE 2-5: Fall Time vs. Capacitive Load.

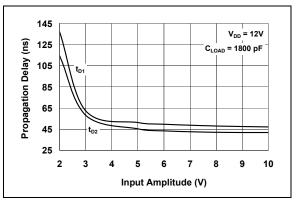
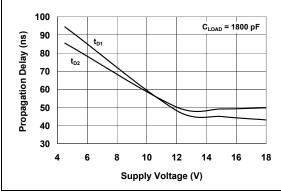


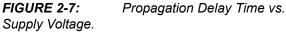
FIGURE 2-6: Amplitude.

Propagation Delay vs. Input

# **Typical Performance Curves (Continued)**

**Note:** Unless otherwise indicated,  $T_A = +25^{\circ}C$  with 4.5V <=  $V_{DD}$  <= 18V.





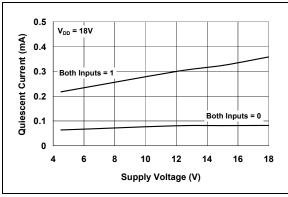


FIGURE 2-8: Quiescent Current vs. Supply Voltage.

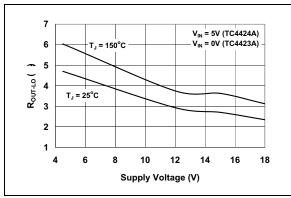


FIGURE 2-9:Output Resistance (OutputLow) vs. Supply Voltage.

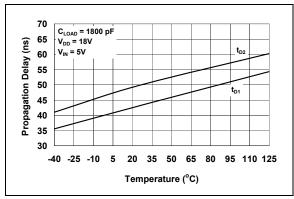


FIGURE 2-10:Propagation Delay Time vs.Temperature.

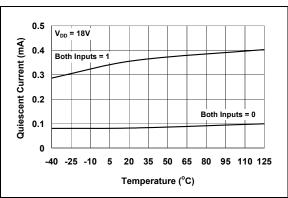


FIGURE 2-11:Quiescent Current vs.Temperature.

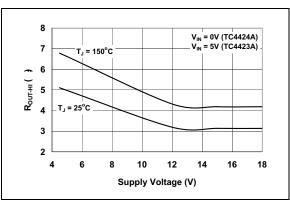
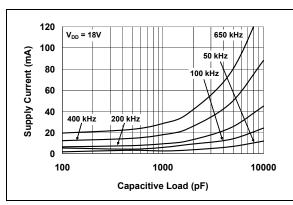
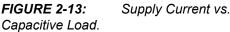


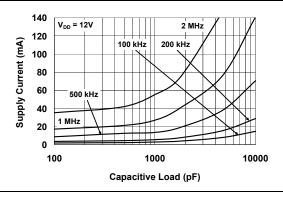
FIGURE 2-12: Output Resistance (Output High) vs. Supply Voltage.

# **Typical Performance Curves (Continued)**

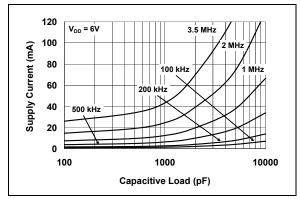
**Note:** Unless otherwise indicated,  $T_A = +25^{\circ}C$  with 4.5V <=  $V_{DD}$  <= 18V.







*FIGURE 2-14:* Supply Current vs. Capacitive Load.



*FIGURE 2-15:* Supply Current vs. Capacitive Load.

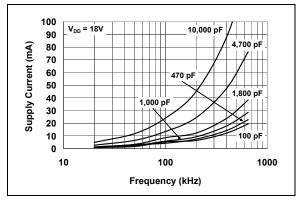


FIGURE 2-16: Frequency.

Supply Current vs.

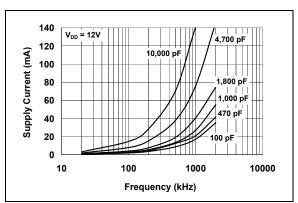


FIGURE 2-17: Supply Current vs. Frequency.

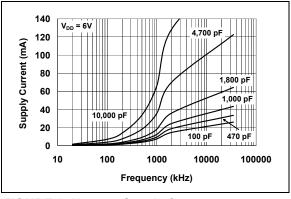
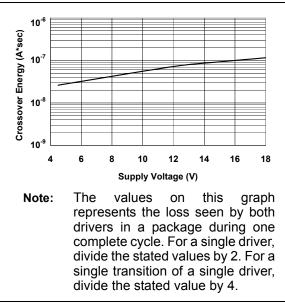


FIGURE 2-18: Frequency.

Supply Current vs.

# **Typical Performance Curves (Continued)**

Note: Unless otherwise indicated,  $T_A = +25^{\circ}C$  with 4.5V <=  $V_{DD}$  <= 18V.



*FIGURE 2-19:* Crossover Energy vs. Supply Voltage.

# 3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 5-1.				
8-Pin PDIP	8-Pin DFN	16-Pin SOIC (Wide)	Symbol	Description
1	1	1	NC	No connection
2	2	2	IN A	Input A
_		3	NC	No connection
3	3	4	GND	Ground
_		5	GND	Ground
_		6	NC	No connection
4	4	7	IN B	Input B
_		8	NC	No connection
—	_	9	NC	No connection
5	5	10	OUT B	Output B
_		11	OUT B	Output B
6	6	12	V <sub>DD</sub>	Supply input
—		13	V <sub>DD</sub>	Supply input
7	7	14	OUT A	Output A
—		15	OUT A	Output A
8	8	16	NC	No connection
_	PAD	—	NC	Exposed Metal Pad

#### TABLE 3-1: PIN FUNCTION TABLE <sup>(1)</sup>

**Note 1:** Duplicate pins must be connected for proper operation.

### 3.1 Inputs A and B

Inputs A and B are TTL/CMOS compatible inputs that control outputs A and B, respectively. These inputs have 300 mV of hysteresis between the high and low input levels, allowing them to be driven from slow rising and falling signals, and to provide noise immunity.

# 3.2 Outputs A and B

Outputs A and B are CMOS push-pull outputs that are capable of sourcing and sinking 3A peaks of current ( $V_{DD}$  = 18V). The low output impedance ensures the gate of the external MOSFET will stay in the intended state even during large transients. These outputs also have a reverse current latch-up rating of 1.5A.

# 3.3 Supply Input (V<sub>DD</sub>)

 $V_{DD}$  is the bias supply input for the MOSFET driver and has a voltage range of 4.5V to 18V. This input must be decoupled to ground with a local ceramic capacitor. This bypass capacitor provides a localized low-impedance path for the peak currents that are to be provided to the load.

# 3.4 Ground (GND)

Ground is the device return pin. The ground pin should have a low-impedance connection to the bias supply source return. High peak currents will flow out the ground pin when the capacitive load is being discharged.

# 3.5 Exposed Metal Pad

The exposed metal pad of the DFN package is not internally connected to any potential. Therefore, this pad can be connected to a ground plane or other copper plane on a printed circuit board to aid in heat removal from the package.

# TC4423A/TC4424A/TC4425A

# 4.0 APPLICATIONS INFORMATION

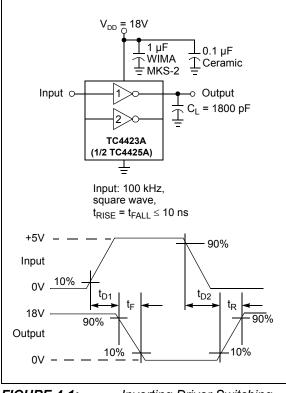


FIGURE 4-1: Inverting Driver Switching Time.

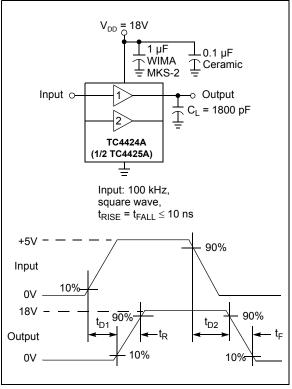
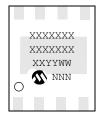


FIGURE 4-2: Non-inverting Driver Switching Time.

# 5.0 PACKAGING INFORMATION

### 5.1 Package Marking Information (Not to Scale)

#### 8-Lead DFN (6x5)



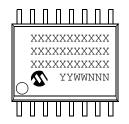
#### 8-Lead PDIP (300 mil)



#### 8-Lead SOIC (150 mil)

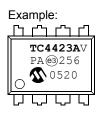


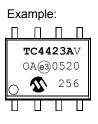
#### 16-Lead SOIC (300 mil)



# Example:







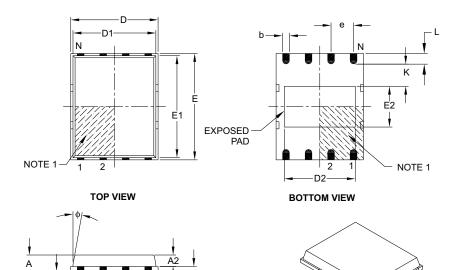
### Example:



Legend	: XXX Y YY WW NNN @3 *	Customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.
	be carrie	nt the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available s for customer-specific information.

# 8-Lead Plastic Dual Flat, No Lead Package (MF) – 6x5 mm Body [DFN-S] PUNCH SINGULATED

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



		Units		MILLIMETERS		
	Dimension Limits			NOM	MAX	
Number of Pins		Ν		8		
Pitch		е		1.27 BSC		
Overall Height		А	-	0.85	1.00	
Molded Package Thickness		A2	-	0.65	0.80	
Standoff		A1	0.00	0.01	0.05	
Base Thickness		A3	0.20 REF			
Overall Length		D	4.92 BSC			
Molded Package Length		D1	4.67 BSC			
Exposed Pad Length		D2	3.85	4.00	4.15	
Overall Width		Е		5.99 BSC		
Molded Package Width		E1		5.74 BSC		
Exposed Pad Width		E2	2.16	2.31	2.46	
Contact Width		b	0.35 0.40 0.47			
Contact Length		L	0.50	0.60	0.75	
Contact-to-Exposed Pad		К	0.20 – –			
Model Draft Angle Top		¢	_	-	12°	

NOTE 2

#### Notes:

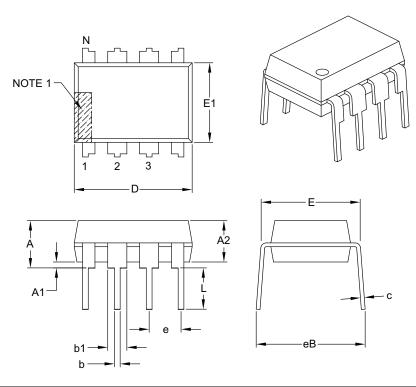
- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package may have one or more exposed tie bars at ends.
- 3. Dimensioning and tolerancing per ASME Y14.5M.
  - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-113B

#### 8-Lead Plastic Dual In-Line (PA) – 300 mil Body [PDIP]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		INCHES		
Dimension	Dimension Limits		NOM	MAX	
Number of Pins	N		8		
Pitch	е		.100 BSC		
Top to Seating Plane	Α	-	-	.210	
Molded Package Thickness	A2	.115	.130	.195	
Base to Seating Plane	A1	.015	-	-	
Shoulder to Shoulder Width	E	.290	.310	.325	
Molded Package Width	E1	.240	.250	.280	
Overall Length	D	.348	.365	.400	
Tip to Seating Plane	L	.115	.130	.150	
Lead Thickness	С	.008	.010	.015	
Upper Lead Width	b1	.040	.060	.070	
Lower Lead Width	b	.014	.018	.022	
Overall Row Spacing §	eВ	_	-	.430	

#### Notes:

1. Pin 1 visual index feature may vary, but must be located with the hatched area.

2. § Significant Characteristic.

3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.

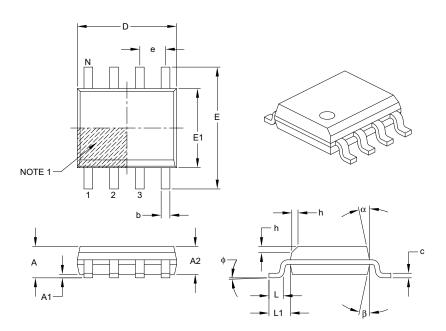
4. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-018B

### 8-Lead Plastic Small Outline (OA) – Narrow, 3.90 mm Body [SOIC]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Din	mension Limits	MIN	NOM	MAX	
Number of Pins	N		8		
Pitch	e		1.27 BSC		
Overall Height	А	-	-	1.75	
Molded Package Thickness	A2	1.25	-	-	
Standoff §	A1	0.10	-	0.25	
Overall Width	E	6.00 BSC			
Molded Package Width	E1	3.90 BSC			
Overall Length	D	4.90 BSC			
Chamfer (optional)	h	0.25	-	0.50	
Foot Length	L	0.40	-	1.27	
Footprint	L1		1.04 REF		
Foot Angle	φ	0°	-	8°	
Lead Thickness	С	0.17 – 0.25			
Lead Width	b	0.31 – 0.51			
Mold Draft Angle Top	α	5° – 15°			
Mold Draft Angle Bottom	β	5°	_	15°	

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. § Significant Characteristic.

3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.

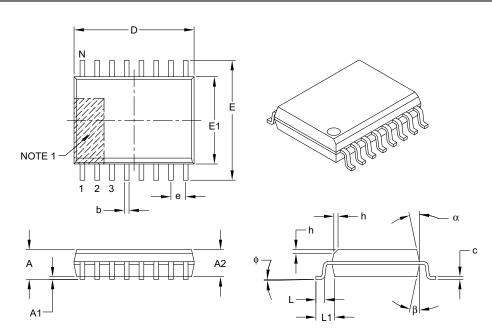
- 4. Dimensioning and tolerancing per ASME Y14.5M.
  - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-057B

#### 16-Lead Plastic Small Outline (OE) – Wide, 7.50 mm Body [SOIC]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		MILLIMETERS		
	Dimension Limits	MIN	NOM	MAX	
Number of Pins	N		16		
Pitch	е		1.27 BSC		
Overall Height	А	-	-	2.65	
Molded Package Thickness	A2	2.05	-	-	
Standoff §	A1	0.10	-	0.30	
Overall Width	E	10.30 BSC			
Molded Package Width	E1	7.50 BSC			
Overall Length	D	10.30 BSC			
Chamfer (optional)	h	0.25	_	0.75	
Foot Length	L	0.40	-	1.27	
Footprint	L1		1.40 REF		
Foot Angle	φ	0°	_	8°	
Lead Thickness	С	0.20 – 0.33			
Lead Width	b	0.31 – 0.51			
Mold Draft Angle Top	α	5° – 15°			
Mold Draft Angle Bottom	β	5°	_	15°	

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. § Significant Characteristic.

3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.

4. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-102B

NOTES:

# APPENDIX A: REVISION HISTORY

# Revision B (April 2007)

- Correct numerous errors throughout document.
- Page 3: Added Package Power Dissipation information about DC Characteristic Table.
- Page 3: Added Note 3 to DC Characteristic Table.
- Page 4: Changed Thermal Resistance for 8L-PDIP device from 125 to 84.6. Changed Thermal Resistance for 8L-SOIC from 155 to 163.
- Page 12: Updated Package Outline Drawing.
- Page 13: Updated Package Outline Drawing.
- Page 14: Updated Package Outline Drawing.
- Page 15: Added 16-Lead SOIC Package Outline
   Drawing
- Page 17: Updated Revision History.

# Revision A (June 2006)

• Original Release of this Document.

NOTES:

# **PRODUCT IDENTIFICATION SYSTEM**

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO. X	<u>xx</u>	<u>xxx</u>	Ex	amples:	
Device Tempe Ran		Tape & Reel	a)	TC4423AVOA:	3A Dual Inverting MOSFET Driver, 8LD SOIC package.
Device:	TC4424A: 3A Dual I	NOSFET Driver, Inverting NOSFET Driver, Non-Inverting	b)	TC4423AVPA:	3A Dual Inverting MOSFET Driver, 8LD PDIP package.
Tomporatura Dongo		10SFET Driver, Complementary	c)	TC4423AVMF:	3A Dual Inverting MOSFET Driver, 8LD DFN package.
Temperature Range: Package: *	MF = Dual, Flat	No-Lead (6x5 mm Body), 8-lead No-Lead (6x5 mm Body), 8-lead	d)	TC4423AVOE:	3A Dual Inverting MOSFET Driver, 16LD SOIC package.
	OA = Plastic SC OA713 = Plastic SC (Tape and OE = Plastic SC	DIC (150 mil Body), 8-Lead DIC (150 mil Body), 8-Lead	a)	TC4424AVOA713:	3A Dual Non-Inverting, MOSFET Driver, 8LD SOIC package, Tape and Reel.
	(Tape and PA = Plastic DI		b)	TC4424AVPA:	3A Dual Non-Inverting, MOSFET Driver, 8LD PDIP package.
			a)	TC4425AVOA:	3A Dual Complementary, MOSFET Driver, 8LD SOIC package.
			b)	TC4425AVPA:	3A Dual Complementary, MOSFET Driver, 8LD PDIP package.
			c)	TC4425AVOE713:	3A Dual Complementary, MOSFET Driver, 16LD SOIC package, Tape and Reel.

NOTES:

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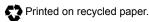
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